TOSHIBA Intelligent Power Module Silicon N Channel IGBT

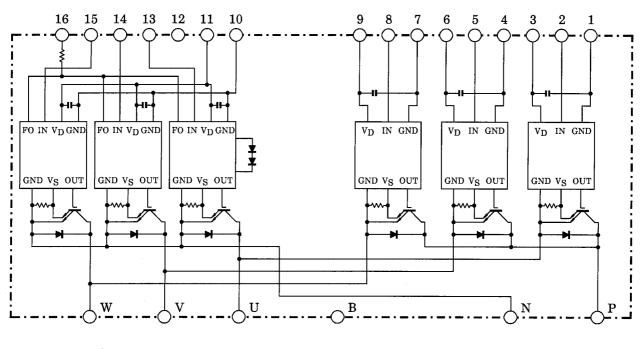
# **MIG75J101H**

# High Power Switching Applications

#### Motor Control Applications

- Integrates inverter & control circuits (igbt drive units, protection units for over-current, under-voltage & over-temperature) in one package.
- The electrodes are isolated from case.
- High speed type IGBT : V<sub>CE</sub> (sat) = 2.5 V (Max.)
  - $t_{off} = 3.0 \ \mu s \ (Max.)$ 
    - $t_{rr} = 0.30 \ \mu s$  (Max.)
- Outline : TOSHIBA 2-110A1A
- Weight : 520 g

#### **Equivalent Circuit**



# Maximum Ratings (T<sub>j</sub> = 25°C)

Stage	Characteristic	Condition	Symbol	Ratings	Unit
Inverter	Supply voltage	P-N power terminal	V <sub>CC</sub>	450	V
	Collector-emitter voltage	_	V <sub>CES</sub>	600	V
	Collector current	Tc = 25°C, DC	Ι <sub>C</sub>	75	Α
	Forward current	Tc = 25°C, DC	IF	75	А
	Collector power dissipation	Tc = 25°C	P <sub>C</sub>	235	W
	Junction temperature	_	Tj	150	°C
Control	Control supply voltage	V <sub>D</sub> -GND terminal	VD	20	V
	Input voltage	IN-GND terminal	V <sub>IN</sub>	20	V
	Fault output voltage	FO-GND (L) terminal	V <sub>FO</sub>	20	V
	Fault output current	FO sink current	I <sub>FO</sub>	14	mA
Module	Operating temperature	_	TC	-20 ~ +100	°C
	Storage temperature range	_	T <sub>stg</sub>	-40 ~ +125	°C
	Isolation voltage	AC 1 minute	V <sub>ISO</sub>	2500	V
	Screw torque	M5	—	3	Nm

# Electrical Characteristics ( $T_j = 25^{\circ}C$ )

## a. Inverter Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	losy	V <sub>CEX</sub> = 600V	T <sub>j</sub> = 25°C	_	_	1	mA
	ICEX		T <sub>j</sub> = 125°C	_	—	20	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	$V_D$ = 15 V, I <sub>C</sub> = 75 A V <sub>IN</sub> = 15 V $\rightarrow$ 0 V	T <sub>j</sub> = 25°C	_	2.0	2.5	v
conector-entitier saturation voltage			T <sub>j</sub> = 125°C	_	2.0	—	
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 75A		-	2.1	3.0	V
	t <sub>on</sub>	V <sub>CC</sub> = 300 V, I <sub>C</sub> = 75 A V <sub>D</sub> = 15 V, V <sub>IN</sub> = 15 V↔0 V		_	1.0	2.0	-
Switching time	t <sub>off</sub>			_	1.2	3.0	
Switching time	t <sub>f</sub>	Inductive load	(Note 1)	_	0.2	0.5	μs
	t <sub>rr</sub>		(Note 1)	_	0.1	0.3	

## b. Control Stage (T<sub>j</sub> = 25°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Control circuit current	High side	I <sub>D (H)</sub>	- V <sub>D</sub> = 15 V	_	8	_	mA
	Low side	I <sub>D (L)</sub>		_	24		
Input-on signal voltage		V <sub>IN (on)</sub>	V <sub>D</sub> = 15 V, I <sub>C</sub> = 75 mA	1.3	1.5	1.7	V
Input-off signal voltage		V <sub>IN (off)</sub>	V <sub>D</sub> = 15 V, I <sub>C</sub> = 75 mA	2.2	2.5	2.8	V
Fault output current	Protection	I <sub>FO (on)</sub>	– V <sub>D</sub> = 15 V	8	10	12	mA
	Normal	I <sub>FO (off)</sub>		_	_	1	
Over current protection trip level	Inverter	OC	V <sub>D</sub> = 15 V, T <sub>j</sub> = 125°C	105	150	_	А
Short circuit protection trip level	Inverter	SC	V <sub>D</sub> = 15 V, T <sub>j</sub> = 125°C	157	225	_	А
Over current cut-off time		t <sub>off (OC)</sub>	V <sub>D</sub> = 15 V	_	5		μs
Over temperature	Trip level	ОТ	- Case temperature	110	118	125	°C
protection	Reset level	OTr		_	98		
Control supply under voltage protection	Trip level	UV		11.0	12.0	12.5	V
	Reset level	UVr		—	12.5	_	
Fault output pulse width		t <sub>FO</sub>	V <sub>D</sub> = 15 V	1	2	3	ms

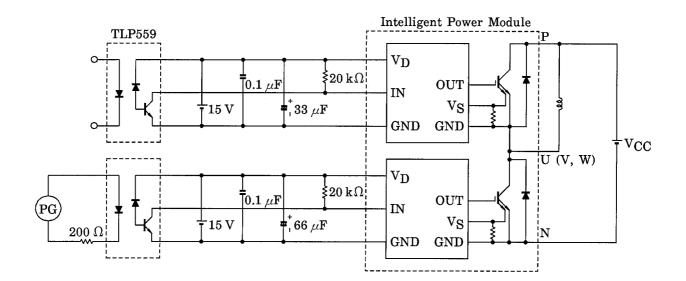
\*1: Duty = 50%

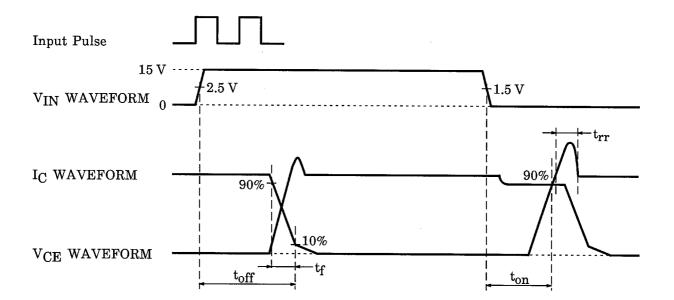
\*2: Duty = 50% (all elements) & fault output current (sink)

#### d. Thermal Resistance (T<sub>j</sub> = 25°C)

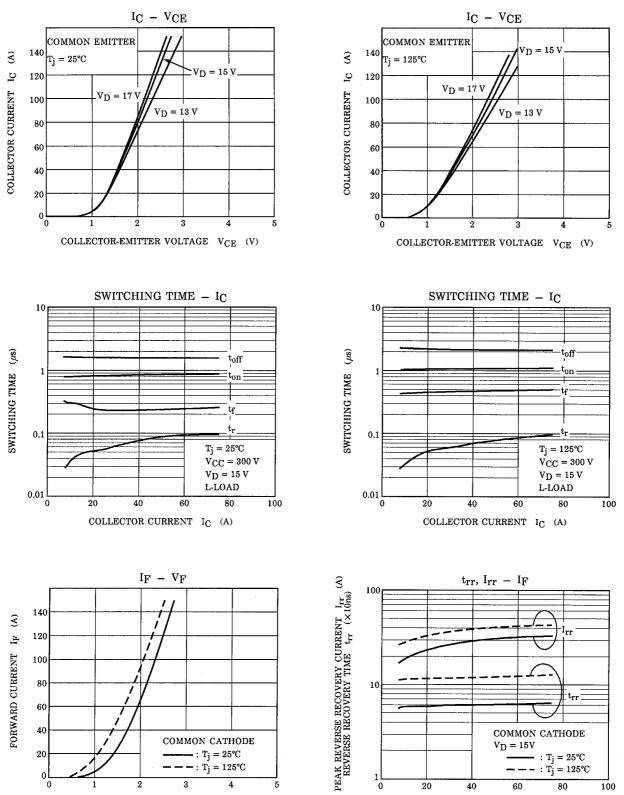
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
		Inverter IGBT stage	_	-	0.553	
Junction to case thermal resistance	<b>D</b> <i>u</i> , <i>a</i> , 5	Inverter FRD stage		1.000	°C / W/	
Sunction to case thermal resistance	R <sub>th (j-c)</sub>	_	_	_	_	°C/W
		_	_		_	
Case to fin thermal resistance	R <sub>th (c-f)</sub>	Compound is applied	-	0.05	-	°C/W

Note 1: Switching time test circuit & timing chart





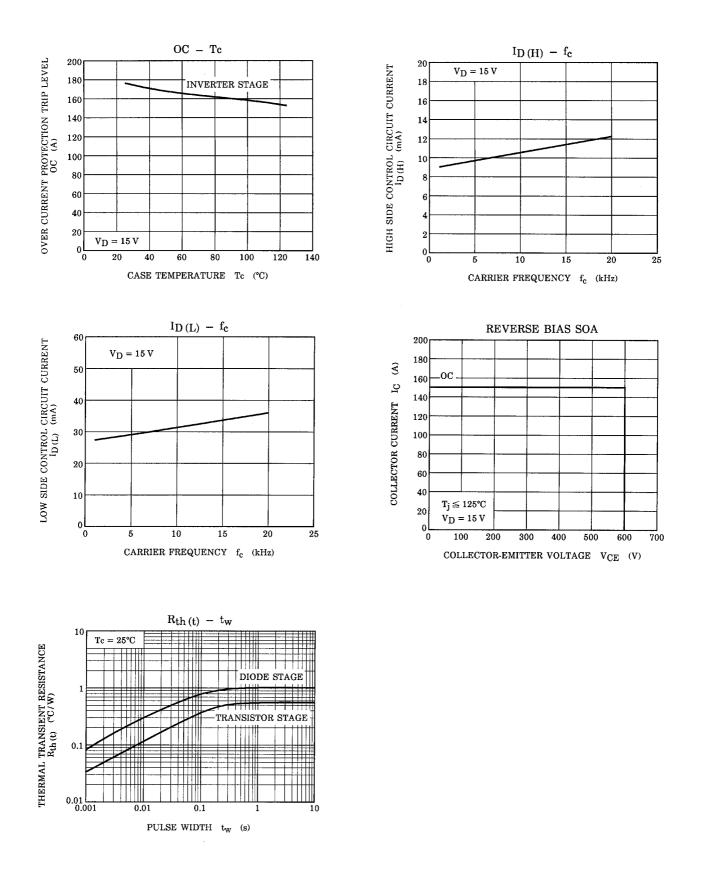
# TOSHIBA



FORWARD CURRENT  $I_F$  (A)

FORWARD VOLTAGE VF (V)

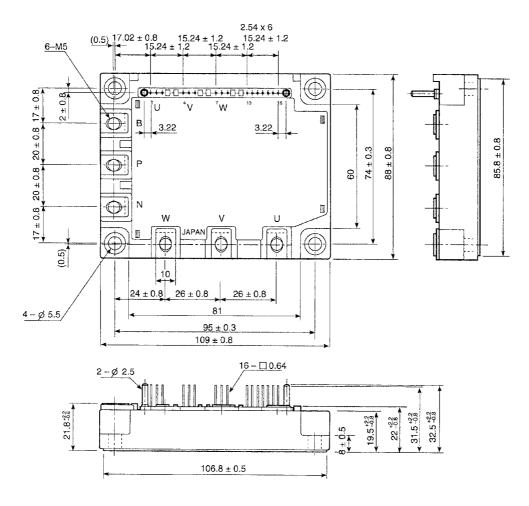
# TOSHIBA



### **Package Dimensions**

TOSHIBA 2-110A1A

Unit: mm



GND IN VD GND IN VD GND IN VD GND VD IN IN IN IN FO (U) (V) (W) (B) (X) (Y) (Z) , 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 Signal Terminal (00000000000000000000)

#### **RESTRICTIONS ON PRODUCT USE**

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.